NSN 5961-01-453-4459

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.300 inches
Terminal Length:
1.000 inches
Overall Diameter:
0.107 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
D0-7
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
3.9 regulator voltage
Current Rating Per Characteristic:
70.00 microamperes source cutoff current horsepower metric
Power Rating Per Characteristic:
250.0 milliwatts forward power dissipation, dc universal
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Terminal Type And Quantity:
Uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0